# 2SB1054

# Silicon PNP triple diffusion planar type

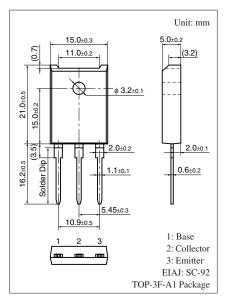
For high power amplification Complementary to 2SD1485

#### Features

- $\bullet$  Excellent collector current  $I_C$  characteristics of forward current transfer ratio  $h_{FE}$
- Wide safe operation area
- $\bullet$  High transition frequency  $f_{\rm T}$
- Full-pack package which can be installed to the heat sink with one screw

| Parameter                             | Symbol           | Rating      | Unit |  |  |  |  |
|---------------------------------------|------------------|-------------|------|--|--|--|--|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -100        | V    |  |  |  |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -100        | V    |  |  |  |  |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub> | -5          | V    |  |  |  |  |
| Collector current                     | I <sub>C</sub>   | -5          | А    |  |  |  |  |
| Peak collector current                | I <sub>CP</sub>  | -8          | А    |  |  |  |  |
| Collector power dissipation           | P <sub>C</sub>   | 60          | W    |  |  |  |  |
| $T_a = 25^{\circ}C$                   |                  | 3           |      |  |  |  |  |
| Junction temperature                  | Tj               | 150         | °C   |  |  |  |  |
| Storage temperature                   | T <sub>stg</sub> | -55 to +150 | °C   |  |  |  |  |

#### Absolute Maximum Ratings $T_C = 25^{\circ}C$



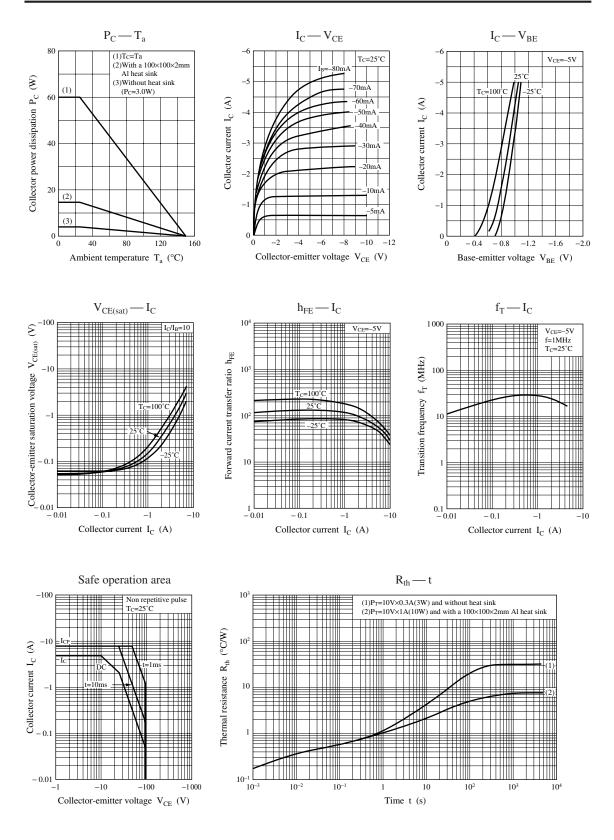
## Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

| Parameter                                    | Symbol               | Conditions   | Min | Тур | Max  | Unit |
|--|----------------------|--|-----|-----|------|------|
| Base-emitter voltage                         | V <sub>BE</sub>      | $V_{CE} = -5 \text{ V}, I_C = -3 \text{ A}$                      |     |     | -1.8 | V    |
| Collector-base cutoff current (Emitter open) | I <sub>CBO</sub>     | $V_{CB} = -100 \text{ V}, I_E = 0$                               |     |     | -50  | μΑ   |
| Emitter-base cutoff current (Collector open) | I <sub>EBO</sub>     | $V_{EB} = -3 V, I_C = 0$   |     |     | -50  | μΑ   |
| Forward current transfer ratio               | h <sub>FE1</sub>     | $V_{CE} = -5 \text{ V}, I_C = -20 \text{ mA}$                    | 20  |     |      | _    |
|  | h <sub>FE2</sub> *   | $V_{CE} = -5 V, I_C = -1 A$                                      | 40  |     | 200  |      |
|  | h <sub>FE3</sub>     | $V_{CE} = -5 \text{ V}, I_C = -3 \text{ A}$                      | 20  |     |      |      |
| Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_{\rm C} = -3$ A, $I_{\rm B} = -0.3$ A                         |     |     | -2.0 | V    |
| Transition frequency                         | f <sub>T</sub>       | $V_{CE} = -5 \text{ V}, I_C = -0.5 \text{ A}, f = 1 \text{ MHz}$ |     | 20  |      | MHz  |
| Collector output capacitance                 | C <sub>ob</sub>      | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$             |     | 170 |      | pF   |
| (Common base, input open circuited)          |                      |  |     |     |      |      |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

| Rank             | R        | Q         | Р          |
|------------------|----------|-----------|------------|
| h <sub>FE2</sub> | 40 to 80 | 60 to 120 | 100 to 200 |



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